

High-frequency Amplifier Transistor (25V, 50mA, 300MHz)

2SC5659 / 2SC4618 / 2SC4098 / 2SC2413K

Features

1) Low collector capacitance. (Cob : Typ. 1.3pF)

2) Low rbb, high gain, and excellent noise characteristics.

Dimensions	(Unit : mm)	
2SC5659	. 1.2 .	
	0.2 0.8 0.2	
ROHM : VMT3	8 0 0.15Max.	(1) Base (2) Emitter
	의	(3) Collector
2SC4618	01	
	<u>'0.8</u> '	
ROHM : EMT3 EIAJ : SC-75A		(1) Emitter (2) Base
	<u>6</u>	(3) Collector
2SC4098		
	1.25	
	2.1	
	0.0	
ROHM : UMT3	0.1to0.4	(1) Emitter
EIAJ : SC-70	Each lead has same dimensions	(2) Base (3) Collector
2SC2413K		
2502413K		
	2.9 2.9	
	2.8	
ROHM : SMT3		(1) Emitter
EIAJ : SC-59	Each lead has same dimensions	(2) Base (3) Collector
		(0) 00100101

●Absolute maximum ratings (Ta=25°C)

			,			
	Parameter	Symbol	Limits	Unit		
Collector-ba	se voltage	Vсво	40	V		
Collector-en	nitter voltage	Vceo	25	V		
Emitter-base	e voltage	Vebo	5	V		
Collector cu	rrent	lc	50	mA		
Collector	2SC5659, 2SC4618	- Pc	0.15	W		
dissipation	2SC4098, 2SC2413K	10	0.2			
Junction ten	nperature	Tj	150	°C		
Storage tem	perature	Tstg	-55 to +150	°C		

•Packaging specifications and hre

Туре	2SC5659	2SC4618	2SC4098	2SC2413K
Package	VMT3	EMT3	UMT3	SMT3
hfe	Р	Р	Р	Р
Marking	A*	A*	A*	A*
Code	T2L	TL	T106	T146
Basic ordering unit (pieces)	8000	3000	3000	3000

* Denotes hfe

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Collector-base breakdown voltage	ВУсво	40	-	-	V	Ic=50μA
Collector-emitter breakdown voltage	BVCEO	25	-	-	V	Ic=1mA
Emitter-base breakdown voltage	ВVево	5	-	-	V	Ιε=50μΑ
Collector cutoff current	Ісво	-	-	0.5	μΑ	Vcb=24V
Emitter cutoff current	Іево	-	-	0.5	μΑ	VEB=3V
Collector-emitter saturation voltage	VCE(sat)	-	0.1	0.3	V	Ic/IB=10mA/1mA
DC current transfer ratio	hfe	82	-	180	-	Vce=6V, Ic=1mA
Transition frequency	f⊤	150	300	-	MHz	Vce=6V, Ie= -1mA, f=100MHz
Output capacitance	Cob	-	1.3	2.2	pF	Vcb=6V, IE=0A, f=1MHz

•Electrical characteristics curves

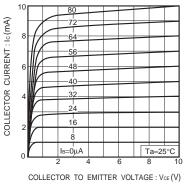


Fig.1 Ground emitter output characteristics

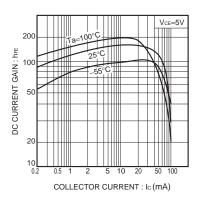


Fig.4 DC current gain vs. collector current (II)

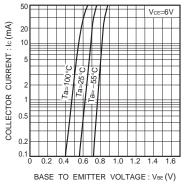


Fig.2 Ground emitter propagation characteristics

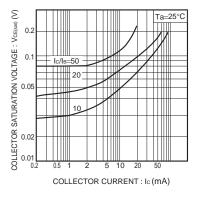


Fig.5 Collector-emitter saturation voltage vs. collector current (I)

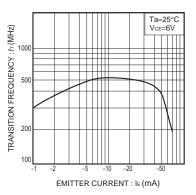
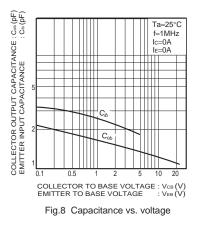


Fig.7 Gain bandwidth product vs.emitter current



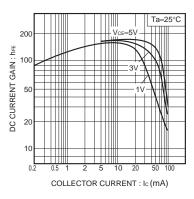


Fig.3 DC current gain vs. collector current (I)

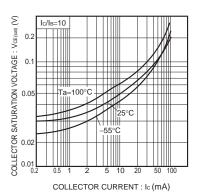


Fig.6 Collector-emitter saturation voltage vs. collector current (II)

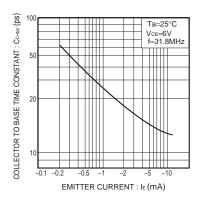


Fig.9 Collector to base time constance vs. emitter current

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